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SEMICONDUCTORS: MEMORY DRAM

Jameco Part#	Manufacturer	Manufacturer Part #	Description	Package Type	Configuration	Price 1
2287743	Samsung Electronics	M395T5160QZ4-YE68(PC2)	IC 395T5160QZ4 DDR2 DIMM SDRAM Buffered 240pin (Module)	DIMM	512M x 72	\$ 14.95
41339	Major Brands	4116-15	IC 4116-15 DRAM 16,384-Bit (16Kx1) 150ns 5V	DIP-16	16K x 1	\$ 2.49
41398	Major Brands	41256-120	IC 41256-120 DRAM 256K-Bit (256Kx1) 120ns w/Page/Nibble Mode	DIP-16	256K x 1	\$ 1.95
2287695	Matsushita Electronic Comp.	41256A-08	IC 41256A-08 DRAM 256K-Bit (256Kx1) 80ns	DIP-16	256K x 1	\$ 0.99
2290567	Vishay	SL41256P-10	IC 41256P-10 DRAM 262,144-Bit (262,144x1) 100ns 5V Low Power	DIP-16	256K x 1	\$ 1.75
41574	Major Brands	41464-10	IC 41464-10 DRAM 256K-Bit (64Kx4) 100ns w/Page Mode (HY53C464S-10)	DIP-18	64K x 4	\$ 2.49
2290535	Samsung Electronics	4164-120	IC 4164-120 NMOS DRAM 64K-Bit (64K x 1) 120ns w/Page Mode	DIP-16	64K x 1	\$ 2.49
41662	Major Brands	4164-150	IC 4164-150 DRAM 262,144-Bit (65,536x4) 150ns w/Page Mode	DIP-16	64K x 4	\$ 2.25
2288023	National Semiconductor	TMS4416-12NL	IC 4416-12 SMOS DRAM 64K-Bit (16Kx4) 120ns 5V	DIP-18	16K x 4	\$ 1.95
2288063	Mitsubishi Electric and Electronics USA	M5M44256BP-8	IC 44256BP-8 CMOS DRAM 1,048,576-Bit (262,144x4) 80ns Fast Page Mode	DIP-20	256K x 4	\$ 4.95
2288031	Toshiba	TC511001AP-70	IC 511001AP-10 CMOS DRAM 1,048,576-Bit (1,048,576x1) 70ns	DIP-18	1M x 1	\$ 4.95